

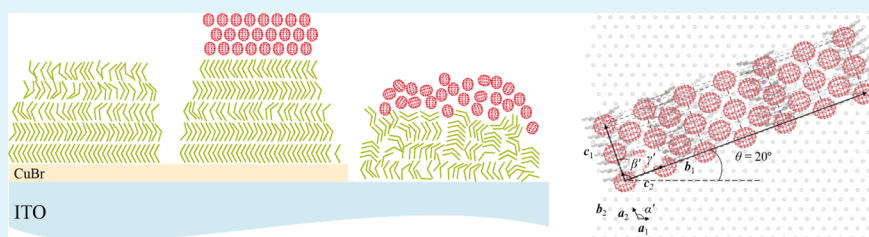
Multilayer Epitaxial Growth of Lead Phthalocyanine and C₇₀ Using CuBr as a Templating Layer for Enhancing the Efficiency of Organic Photovoltaic Cells

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S Supporting Information



ABSTRACT: The molecular orientation and crystallinity of donor and acceptor molecules are important for high-efficiency organic photovoltaic cells (OPVs) because they significantly influence both the absorption of light and charge-transport characteristics. We report that the templating effect extends to multilayers to increase the crystallinity and to modify the orientation of the crystals of lead phthalocyanine (PbPc) and C₇₀ layers at the same time by adopting CuBr as a new templating layer on indium tin oxide (ITO). The formation of a monoclinic phase with a preferred orientation of (320) for PbPc and a fcc phase with a preferred orientation of (220) for C₇₀ on the PbPc layer is revealed by X-ray diffraction (XRD) patterns. The multilayer epitaxy results in an increase of the exciton diffusion lengths from 5.6 to 8.8 nm for PbPc and from 6.9 to 13.8 nm for C₇₀ to enhance the power conversion efficiency (PCE) of the planar heterojunction OPVs composed of PbPc and C₇₀ from 1.4 to 2.3%. The quasi-epitaxy model is proposed to explain the multilayer epitaxy.

KEYWORDS: organic photovoltaic, templating layer, organic epitaxy, copper bromide, lead phthalocyanine, C₇₀

1. INTRODUCTION

Tremendous progress has been made in small-molecule-based organic photovoltaic cells (OPVs) in recent years, demonstrating a power conversion efficiency (PCE) up to ~8.9% using the solution process^{1–4} and ~8.1% using the vacuum process.^{5–8} For the next leap, many researchers are paying attention to the control of the crystal structure and orientation of the molecules because the optical and electrical characteristics of organic films are strongly connected with the crystal structure. The use of templating layers has been considered to be an effective way to control the crystal structure and molecular orientation using intramolecular interactions.^{9–12} The molecule–substrate bonding resulting from the electrostatic interactions between molecules and anions in ionic compounds is known to be the driving force to control the crystal structure and to form the preferred orientation of organic molecules.^{13–16} Recently, CuI has been successfully used as a templating material to achieve significant enhancement of PCE with classical donor materials.^{17–24} However, until now, templating effects have been confined on donor materials deposited on the templating layer. A way to control the phase of the acceptor materials

deposited on the donor materials is needed for higher efficiency OPVs.

Here, we demonstrate a multilayer epitaxy by employing CuBr as a templating layer and lead phthalocyanine (PbPc) and C₇₀ as the donor and acceptor molecules, respectively. PbPc formed the monoclinic phase with a (320) preferred orientation on CuBr, and the Q-band absorption located in the near-IR region of the molecules is developed by the templating effects.²¹ In addition, C₇₀ formed the face-centered cubic (fcc) phase with the preferred orientation of (220) when deposited on the crystalline PbPc grown on the CuBr templating layer. The multilayer epitaxy results in the increase of the exciton diffusion lengths (L_D) and the absorption in both layers to enhance the PCE of the planar heterojunction OPVs composed of PbPc and C₇₀ from 1.4 to 2.3%.

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2. EXPERIMENTAL SECTION

The organic solar cells used in this study have the following structure: ITO/PbPc (20 nm)/C₇₀ (50 nm)/bathocuproine (BCP) (8 nm)/Al (100 nm) with and without a 3 nm thick CuBr layer between the ITO and PbPc layers to investigate the templating effect. The ITO-coated glass substrate was successively cleaned with acetone and isopropyl alcohol, and the substrate was exposed to UV-O₃ for 10 min before use. All of the organic layers were deposited using thermal evaporation at a base pressure of ca. 10⁻⁷ Torr with a rate of 1 Å/s. The CuBr layer was also deposited using thermal evaporation onto the substrate at a rate of 0.2 Å/s. The aluminum metal cathode was deposited with a rate of 4 Å/s. All of the layers were successively evaporated without breaking the vacuum. The devices had active areas of 2 × 2 mm². A patterned insulator on the ITO and the top cathode deposited through a shadow mask defined the cell area. After fabrication, the devices were encapsulated using epoxy resin with glass cans under an N₂ environment. The photovoltaic properties of the devices were measured with an AM 1.5G 100 mW cm⁻² solar-simulator (300 W Oriol 69911A) light source and a source measurement unit (Keithley 237). The measurement setup was calibrated with a National Renewable Energy Laboratory-certified reference Si solar cell covered with a KG-5 filter before every measurement. More than eight cells for each device structure were fabricated, and the mean values of the photovoltaic performances and standard deviations were obtained. The UV-vis absorption spectra of films were recorded with a VARIAN Cary 5000 UV-vis spectrophotometer. The films were thermally evaporated on UV-O₃-treated ITO substrates. The crystalline structures were investigated by synchrotron X-ray diffraction measurements at the SA X-ray scattering beamline for materials science at Pohang Light Source II (PLS-II). The X-ray wavelength was 1.071 Å (11.58 KeV) at an incident angle of 0.1°.

3. RESULTS AND DISCUSSION

Figure 1 shows the current density–voltage (*J*–*V*) characteristics of the devices measured under light and dark conditions

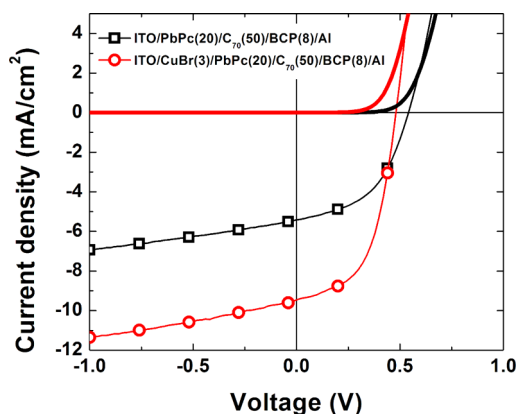


Figure 1. *J*–*V* characteristics the OPVs with and without the CuBr layer. The control device (black square) is composed of ITO/PbPc (20 nm)/C₇₀ (50 nm)/BCP (8 nm)/Al. The device with a 3 nm thick CuBr (red circle) layer inserted between the ITO and PbPc layers in the control device is shown.

using the illumination of an AM 1.5G 100 mW cm⁻² solar-simulated light source. The photovoltaic parameters of the devices are summarized in Table 1. *J*_{SC} was mainly increased by the insertion of CuBr from 5.53 to 9.44 mA cm⁻², and the fill factor (*FF*) was also increased from 0.49 to 0.52. As a result, PCE showed a considerable enhancement of over 1.6 times from 1.45 to 2.34% with the insertion of the CuBr layer despite the slightly reduced open-circuit voltage (*V*_{OC}) (from 0.53 to 0.48). The origin of the reduction of *V*_{OC} is not clear yet, but it can be discussed on the basis of the variation of the diode parameters in the devices. *V*_{OC} in the Shockley diode equation can be expressed as follows²⁵

$$V_{OC} = \frac{nkT}{q} \ln\left(\frac{J_{SC}}{J_S}\right) \quad (1)$$

where *n* is the ideality factor, *k* is the Boltzmann constant, *q* is the elementary charge, and *J*_S is the dark saturation current density. The diode parameters are extracted from the dark *J*–*V* characteristic curves and displayed in Table 1. The *J*_S value increases from 1.57 × 10⁻⁴ to 3.05 × 10⁻⁴ mA/cm² and *n* decreases from 2.41 to 1.98 when the CuBr templating layer is used. The calculated *V*_{OC} values using eq 1 are 0.53 and 0.65 V with and without the CuBr templating layer, respectively, and this tendency is consistent with the change of the measured *V*_{OC} values of the devices with and without the CuBr layer. Because *J*_S is a function of the difference between the highest occupied molecular orbital (HOMO) level of the donor and the lowest unoccupied molecular orbital (LUMO) level of the acceptor,²⁵ the change in the energy-level alignment of the active layers with a CuBr templating layer is a possible origin of the reduction of *V*_{OC}. Different orientation and different phases have been reported to give different HOMO levels, resulting in different *V*_{OC} values.^{26,27}

To understand the templating effect, the absorption spectra and the incident photon-to-current efficiency (IPCE) spectra of the ITO/PbPc (20 nm) and ITO/CuBr (3 nm)/PbPc (20 nm) films were measured and are shown in Figures 2 and 3, respectively. The absorption peak at a wavelength of 900 nm in the Q-band absorption is more pronounced at the expense of the reduced absorption peak at 740 nm by the insertion of the CuBr layer. This change can be explained by the formation of the monoclinic phase with a (320) preferred orientation, indicating that the CuBr layer acts as a templating layer for the PbPc molecules to enhance the crystallinity of the PbPc film.²¹ The IPCE spectrum of the device with the CuBr layer is also broadened in the Q-band region. However, the ratio of the peak intensities at 740 and 900 nm in the IPCE spectrum of the device with CuBr is different from the ratio in the absorption spectrum of the ITO/CuBr (3 nm)/PbPc (20 nm) film. The optical simulation of the devices showed that the difference did not originate from an optical interference effect resulting from stacking additional C₇₀, BCP, and Al layers. The difference can

Table 1. Photovoltaic Parameters of the Solar Cells under AM 1.5G 1 Sun Illumination^a

	PCE (%)	<i>J</i> _{SC} (mA/cm ²)	<i>V</i> _{OC} (V)	<i>FF</i>	<i>R</i> _p (Ω cm ²)	<i>R</i> _s (Ω cm ²)	<i>n</i>	<i>J</i> _S (mA/cm ²)	calculated <i>V</i> _{OC} (V)
ITO/PbPc(20)/C70(50)/BCP(8)/Al	1.45 ± 0.02	5.53 ± 0.08	0.53 ± 0.02	0.49 ± 0.01	6.47 × 10 ⁶	6.64	2.41	1.57 × 10 ⁻⁴	0.65
ITO/CuBr(3)/PbPc(20)/C70(50)/BCP(8)/Al	2.34 ± 0.10	9.44 ± 0.17	0.48 ± 0.01	0.52 ± 0.03	2.41 × 10 ⁵	9.01	1.98	3.05 × 10 ⁻⁴	0.53

^aThe *J*_S, *R*_p, and *R*_s values were extracted from dark *J*–*V* curves using the Schokley diode equation.

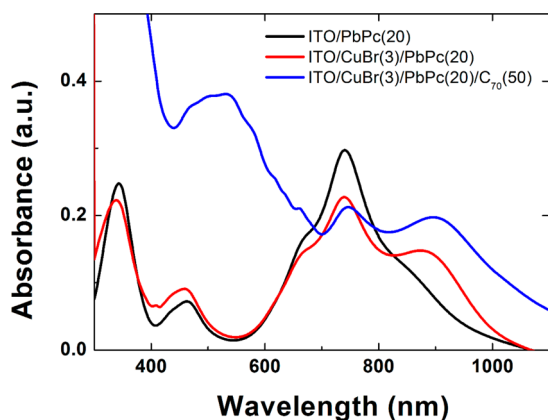


Figure 2. Absorbance spectra of the films with the structures of ITO/PbPc (20 nm), ITO/CuBr (3 nm)/PbPc (20 nm), and ITO/CuBr (3 nm)/PbPc (20 nm)/C₇₀ (50 nm) are represented by the black, red, and blue lines, respectively.

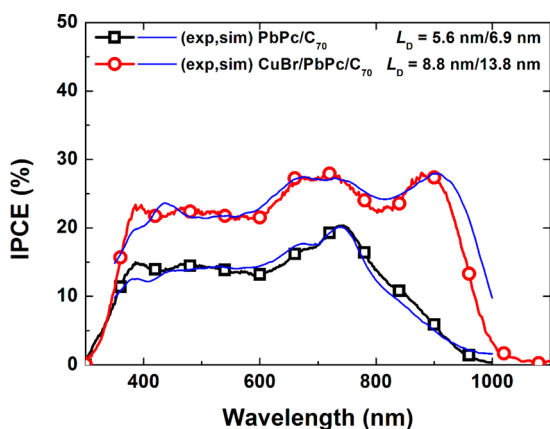


Figure 3. Measured IPCE spectra of the control device (black square) and the device with the CuBr (red circle) templating layer are displayed, and the simulated IPCE spectra using the L_D values shown in the legend are also displayed by the blue lines.

instead be understood from the absorption spectrum of the ITO/CuBr (3 nm)/PbPc (20 nm)/C₇₀ (50 nm) film, as shown in Figure 2. Surprisingly, the absorption peak at a wavelength of 900 nm is more broadened and the absorption intensity is also increased after the deposition of C₇₀ onto the PbPc layer. In contrast, the absorption peak at a wavelength of 740 nm is reduced again after the deposition of C₇₀. The ratio of the two absorption peak intensities is now in very good agreement with the IPCE spectrum. This result strongly suggests that the PbPc molecules near the surface are rearranged after the deposition of C₇₀ onto the PbPc layer. In addition to the modification of the PbPc absorption, the IPCE was also improved in the absorption region of C₇₀ by inserting the CuBr layer, implying that the monoclinic phase of the PbPc layer formed by the CuBr interlayer acts as a templating layer for C₇₀. To the best of our knowledge, this is the first time an organic multilayer epitaxy with both donors and acceptors in OPVs using a templating layer has been reported. This effect was not observed in the device based on C₆₀. Even though J_S was increased significantly in the C₆₀-based device by inserting the CuBr layer, the IPCE coming from the C₆₀ absorption did not change much (Supporting Information Figure S1). The difference in the lattice constants of the bulk crystal of C₆₀ and C₇₀ is a possible origin of the different behaviors. The

lattice-matching condition between the monoclinic phase of PbPc and the fcc and hexagonal close-packed (HCP) phases of C₆₀ was not found from the calculation of dimensionless potential, indicating that quasi-epitaxial growth is not allowed between PbPc and C₆₀.

The formation of the crystals in the PbPc and C₇₀ layers resulted in the increase of the L_D values in the layers, increasing the J_{SC} or IPCE. The L_D values in the organic layers were extracted from the fitting of the measured IPCEs using the transfer matrix method with the L_D values as the parameters.²⁸ For the extraction of L_D , the refractive indices of the 60 and 20 nm thick PbPc films grown on ITO were used for the ITO/CuBr/PbPc and ITO/PbPc films, respectively, because they have similar absorption spectra.²⁹ The fitting results in Figure 3 showed that the L_D value of the PbPc layer increased from 5.6 ± 0.08 to 8.8 ± 0.13 nm by inserting the CuBr layer, which is consistent with previous results.¹⁸ Moreover, the L_D value of the C₇₀ layer was improved by almost a factor of 2, from 6.9 ± 0.10 to 13.8 ± 0.21 nm, also by the insertion of the CuBr layer. As a result, the J_{SC} value of the device increased by 1.7 times, from 5.53 to 9.44 mA cm⁻².

The structural change of the molecules was investigated using the X-ray diffraction (XRD) patterns shown in Figure 4a. The diffraction pattern of the 20 nm thick PbPc layer deposited on an ITO substrate showed two peaks near $Q = 9$ and 11.67 nm⁻¹, which can be assigned as the mixture of the (320)-oriented monoclinic phase ($Q = 8.81$ nm⁻¹), the (1 $\bar{2}$ 1)-oriented monoclinic phase ($Q = 9.12$ nm⁻¹), and the (130)-oriented triclinic phase ($Q = 11.67$ nm⁻¹).^{21,29} When the PbPc was grown on the ITO/CuBr (3 nm), the crystallinity of the monoclinic phase and the (1 $\bar{2}$ 1)-oriented triclinic phase was increased and the amount of the (130)-oriented triclinic phase was reduced. However, the 50 nm thick C₇₀ layer deposited on ITO has a fcc structure with a (111) preferred orientation identified by the diffraction peak at $Q = 7.36$ nm⁻¹. Interestingly, the intensity of the C₇₀ peaks was intensified and the PbPc peaks disappeared when the C₇₀ layer was grown on the ITO/PbPc layer. This fact indicates that the crystallinity of the underlying PbPc layer was demolished by the deposition of the C₇₀ on top of PbPc, clearly demonstrating that the overlayer of C₇₀ significantly modified the structure of the underlying layer. In contrast, the crystallinity of the PbPc layer grown on the ITO/CuBr remained with slight modification of the structure after the deposition of the C₇₀ layer. Furthermore, the diffraction peak near $Q = 9$ nm⁻¹ of the PbPc layer becomes stronger after the deposition of the C₇₀ layer onto the PbPc film, strongly suggesting that the crystallinity of the PbPc layer was increased by the deposition of the C₇₀ layer, which was manifested from the comparison of the intensities of the peaks near $Q = 9$ nm⁻¹ in Figure 4b. In addition, the (220)-oriented fcc C₇₀ phase increased at the expense of the reduced amount of the (111)-oriented fcc phase in the C₇₀ layer. These results are consistent with the increase of the absorption intensity at a wavelength of 940 nm via the deposition of C₇₀. This kind of reconstruction of the organic molecules during Stranski–Krastanov growth in a heteroepitaxy system was also reported by Barrera et al.³⁰ The crystalline structure can be modified by the strain energy induced from the lattice mismatch between the substrate and overlayer in an organic heteroepitaxy system because organic films are softer than inorganic films. These results can be summarized as follows: (1) CuBr acts as a templating layer to increase the crystallinity of the PbPc layer, (2) the crystalline PbPc layer acts as a templating layer for C₇₀

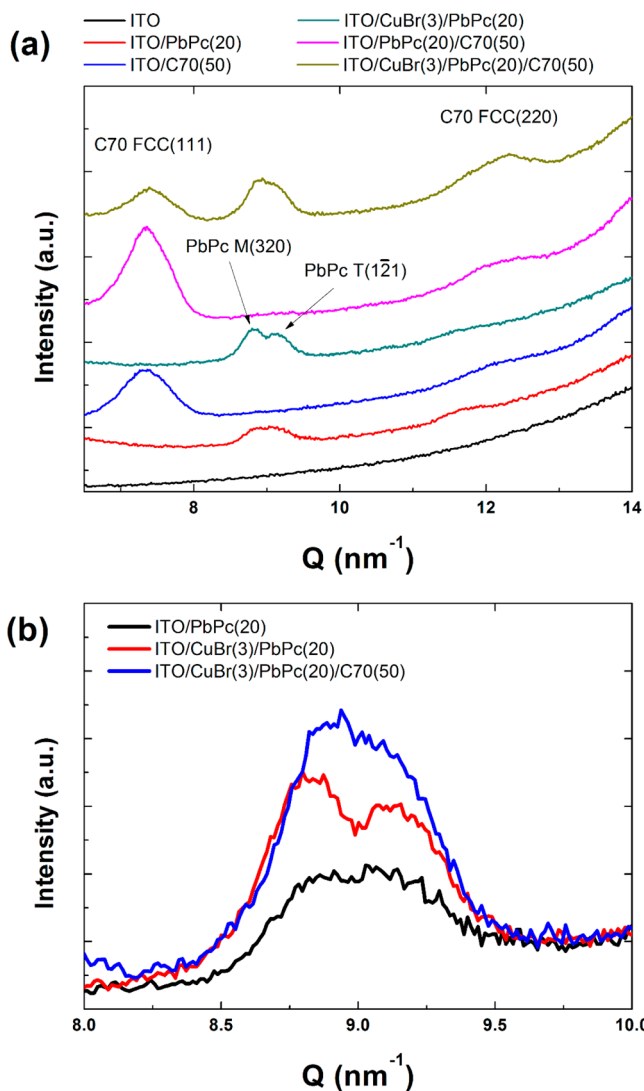


Figure 4. (a) XRD profiles of the films with the following structures: ITO/PbPc (20 nm), ITO/CuBr (3 nm)/PbPc (20 nm), ITO/C₇₀ (50 nm), ITO/PbPc (20 nm)/C₇₀ (50 nm), and ITO/CuBr (3 nm)/PbPc (20 nm)/C₇₀ (50 nm). The peaks of monoclinic PbPc with a (320) orientation and fcc C₇₀ with (111) and (220) orientations are also displayed. (b) Comparison of the peaks of the ITO/PbPc (20 nm), ITO/CuBr (3 nm)/PbPc (20 nm), and ITO/CuBr (3 nm)/PbPc (20 nm)/C₇₀ (50 nm) films near $Q = 9 \text{ nm}^{-1}$.

molecules to form crystals with a preferred (220) orientation, and (3) the crystallinity of the PbPc bottom layer is increased by the deposition of the C₇₀ overlayer. The growth mode is schematically represented by the cartoon images in Figure 5.

The templating effect can be explained by the model of quasi-epitaxial growth in organic films, where the dimensionless potential, V/V_0 , representing the lattice matching between the substrate and the overlayer, is used as the parameter.¹⁵ The value of V/V_0 is determined by the degree of commensurism between the overlayer and the substrate in the range $-0.5 \leq V/V_0 \leq 1$. $V/V_0 = 1$ for incommensurism, $V/V_0 = 0.5$ for coincidence, and $V/V_0 = 0$ and $V/V_0 = -0.5$ for commensurism on nonhexagonal and hexagonal substrates, respectively. The lattice parameters of zinc blende CuBr, monoclinic PbPc, and fcc C₇₀ are summarized in Table 2.^{31–33} The potential V/V_0 values between the (111) plane of the CuBr crystal and the (320) plane of the monoclinic PbPc crystal and between the

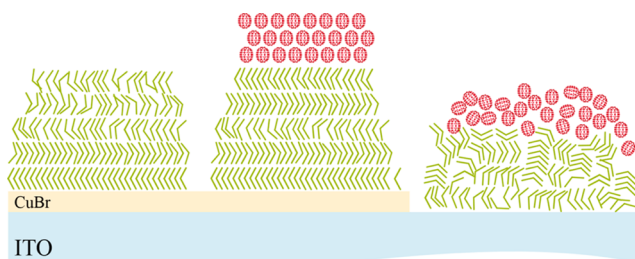


Figure 5. Cartoon image of multilayer epitaxy film composed of ITO/CuBr/PbPc, ITO/CuBr/PbPc/C₇₀, and ITO/PbPc/C₇₀.

Table 2. Lattice Parameters of Zinc Blende CuBr, Monoclinic PbPc, and fcc C₇₀

	a (Å)	b (Å)	c (Å)	$\alpha = \beta = \gamma$ (deg)
CuBr	5.695	5.695	5.695	90
PbPc monoclinic	25.48	25.48	3.73	90
C ₇₀ fcc	14.89	14.89	14.89	90

(320) plane of the monoclinic PbPc crystal and the (220) plane of the fcc C₇₀ crystal were calculated against the azimuthal angle (θ) and displayed in Figure 6a. The angle θ was defined as the angle between vectors a_1 and b_1 , with b_1 and c_1 defining the

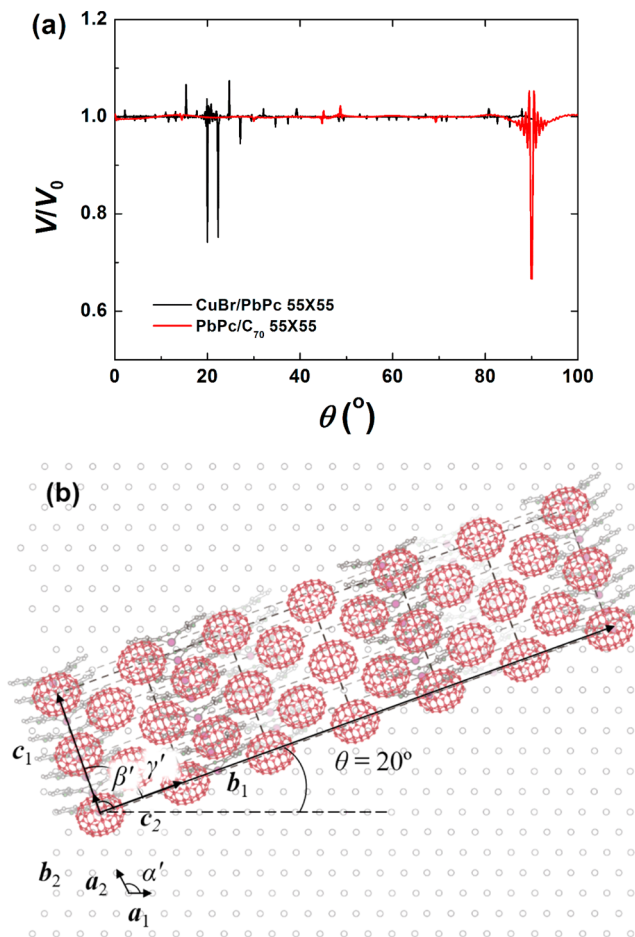


Figure 6. (a) Calculated dimensionless potential, V/V_0 , of CuBr (111)/PbPc monoclinic (320) and PbPc monoclinic (320)/C₇₀ FCC (220). (b) Schematic representation of PbPc monoclinic (320) and C₇₀ fcc (110) unit cells on zinc blende CuBr (111).

azimuthal angles between the overlayer and substrate in Figure 6b. The size of the overlayer was 55×55 . The results clearly show that the minimum potential between the (111) plane of the CuBr crystal and the (320) plane of the monoclinic PbPc crystal are derived at an angle of 20° . The minimum potential between the (320) plane of the monoclinic PbPc crystal and the (220) plane of the C_{70} crystal was obtained at an angle of 90° . The arrangement of CuBr, PbPc, and C_{70} are schematically represented in Figure 6b, exhibiting the multilayer epitaxy.

4. CONCLUSIONS

We demonstrated multilayer epitaxy composed of ITO/CuBr/PbPc/ C_{70} and successfully fabricated OPVs with multilayer epitaxy films. The CuBr layer worked well as a templating layer to form the monoclinic PbPc molecules. In addition, the crystallized PbPc molecules act as a templating layer for the C_{70} overlayer. As a result, the L_D values of the PbPc and C_{70} layers were improved at the same time, from 5.6 to 8.8 nm for PbPc and from 6.9 to 13.8 nm for C_{70} . As a result, the OPV device with CuBr showed a 1.6-fold enhancement in the PCE, which resulted from the increase in the J_{SC} value. Furthermore, the results from the calculations of the dimensionless potential, V/V_0 , for the layers show that the templating effects of each layer can be explained by quasi-epitaxial growth.

The increment of the exciton diffusion length in both donor and acceptor layers has been a major issue in increasing the short-circuit current in organic solar cells. The multilayer epitaxy demonstrated in this study not only explains the origin of the effect of the templating layer on the organic (donor) layer to control its crystal structure but also extends the concept of epitaxy to the organic/organic multilayers to improve the light harvesting from the overlying organic (acceptor) layer. This multilayer epitaxy method can easily be extended to other sets of materials with known lattice parameters of organic crystals and will generally contribute to finding a proper combination of materials, for instance, to develop new templating materials and acceptor molecules for a given excellent donor material or vice versa to improve the performance of OPVs.

■ ASSOCIATED CONTENT

Supporting Information

J - V characteristic curves and IPCE spectra of the organic solar cells with C_{60} measured with an AM 1.5G 100 mW cm^{-2} solar-simulator light source. This material is available free of charge via the Internet at <http://pubs.acs.org>.

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Notes

The authors declare no competing financial interest.

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